Avalanche Photodiodes

For Industrial & Analytical Applications

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AVALANCHE PHOTODIODES

Avalanche Photodiodes Silicon APDs



Avalanche Photodiodes – Silicon APDs

Applications

- Laser range finder
- Scanning video imager
- Confocal microscope
- Free space communication
- Spectrophotometers
- Fluorescence detection
- Luminometer
- DNA sequencer
- Particle sizing

Features and Benefits

- Low noise
- High gain
- High quantum efficiency
- Built-in TE-cooler option
- Various optical input options
- Customization available upon request

Product Description

These rear entry "reach-through" silicon APDs offer the best compromise in terms of cost and performance for applications requiring high speed and low noise photon detection from 400 nm up to 1100 nm. They feature low noise, high quantum efficiency and high gain while maintaining reasonably low operating voltage. The active area varies from 0.5 mm to 3 mm to accommodate a large variety of applications.

The "S" series of the C30902 family of APDs can be used in either their normal linear mode $(V_R < V_{BR})$ or for photon counter in the Geiger mode $(V_R > V_{BR})$. This series is particularly well-suited for ultra-sensitive photon measurements in biomedical and analytical instruments. Precise temperature control can be achieved with a thermo-electric cooler which can be used to improve noise and responsivity or to maintain constant responsivity over a wide range of ambient temperature.

These APDs can also be incorporated into a hermetically-sealed TO-8 package with ultra-low noise preamplifier (C30659 series APD receivers) and thermo-electric cooler (LLAM series receivers) for optimum signal to noise performance.

Technical Specification

Avalanche Photodiodes – Silicon APDs

	Active Diameter	Capaci- tance	Rise/Fall Time	Dark Current	Breakdown Voltage min	Breakdown Voltage max	Temp. Coefficient	Typical	Responsivity 830 nm	Responsivity 900 nm	Responsivity 1060 nm	NEP		
Unit	mm	pF	ns	nA	٧	V	V/° C	Gain	A/W	A/W	A/W	fW/√Hz)	Package	
C30817EH	0.8	2	2	50	300	475	2.2	120	-	75	-	13	TO-5	
C30884E	0.8	4	1	100	190	290	1.1	100	-	63	8	13	TO-5	
C30902BH	0.5	1.6	0.5	15	185	265	0.7	150	77	60	-	3	Ball lens TO-18	
C30902EH	0.5	1.6	0.5	15	185	265	0.7	150	77	60	-	3	TO-18, flat window	
C30902EH-2	0.5	1.6	0.5	15	185	265	0.7	150	77	60	-	3	TO-18, built-in 905 nm filter	
C30902SH	0.5	1.6	0.5	15	185	265	0.7	250	128	108	-	0.9	TO-18, flat window	
C30902SH-2	0.5	1.6	0.5	15	185	265	0.7	250	128	108	-	0.9	TO-18, built-in 905 nm filter	
C30916EH	1.5	3	3	100	315	490	2.2	80	-	50	12	20	TO-5	
C30954EH	0.8	2	2	50	300	475	2.4	120	-	75	36	13	TO-5	
C30955EH	1.5	3	2	100	315	490	2.4	100	-	70	34	14	TO-5	
C30956EH	3	10	2	100	325	500	2.4	75	-	45	25	25	TO-8	

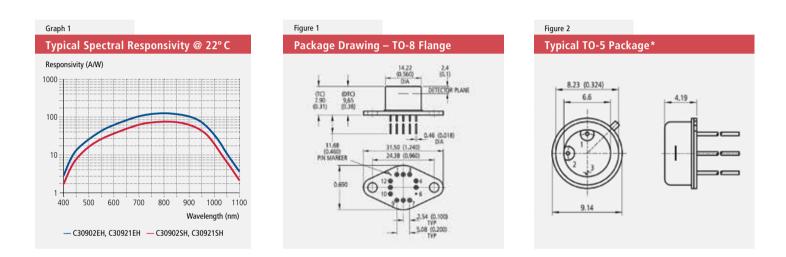
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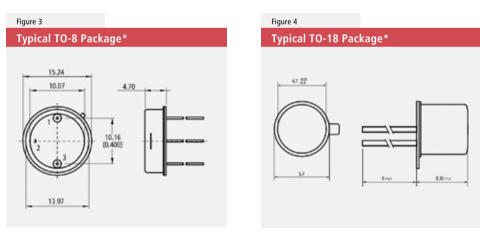
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Product Table Silicon APD – TE-Cooled

	Active Diameter	Active Area	Total Capacitance	Rise/Fall Time	Dark Current	Breakdown Voltage min	Breakdown Voltage max	Temperature Coefficient	Typical Gain	Responsivity 830 nm	Responsivity 900 nm	Responsivity 1060 nm	Noise Current	
Unit	mm	mm ²	pF	ns	nA	V	۷			A/W	A/W	A/W	pA/sqrt(Hz)	Package
C30902SH-TC	0.5	0.2	1.6	0.5	2	225	-	0.7	250	128	108	-	0.04	TO-8 flange
C30902SH-DTC	0.5	0.2	1.6	0.5	1	225	-	0.7	250	128	108	-	0.02	TO-8 flange
C30954EH-TC	0.8	0.5	2	2	8	300	475	2.4	120	-	75	-	0.2	TO-8 flange
C30955EH-TC	1.5	1.8	3	2	15	315	490	2.4	100	-	70	-	0.2	TO-8 flange
C30956EH-TC	3	7	10	2	15	325	500	2.4	75	-	45	-	0.2	TO-8 flange

TC stands for single stage cooler, operating temperature 0° C DTC stands for double stage cooler, operating temperature -20° C





*Note: Package dimensions for indication only. Exact package dimensions can be found on products datasheets.

